TOSHIBA Transistor Silicon NPN Triple Diffused Type

# 2SD2440

#### **Switching Application**

Unit: mm

• High breakdown voltage:  $V_{CBO} = 100 \text{ V}$  :  $V_{EBO} = 18 \text{ V}$ 

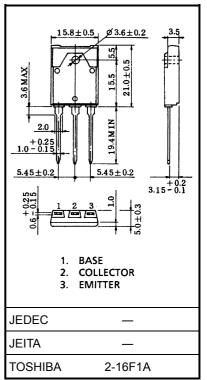
• Low saturation voltage: VCE (sat) = 1.2 V (max) (IC = 5 A, IB = 1 A)

• High speed:  $t_f = 1 \mu s$  (typ.) ( $I_C = 5 A$ ,  $I_B = \pm 0.5 A$ )

• High DC current gain:  $h_{FE} = 200$  (min) ( $V_{CE} = 5$  V,  $I_{C} = 0.5$  A)

### **Maximum Ratings (Ta = 25°C)**

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		$V_{CBO}$	100	V	
Collector-emitter voltage		V <sub>CEO</sub>	60	V	
Emitter-base voltage		V <sub>EBO</sub>	18	V	
Collector current	DC	Ic	6	Α	
	Pulse	I <sub>CP</sub>	12		
Base current		Ι <sub>Β</sub>	2	Α	
Collector power dissipation		Pc	40	W	
(Tc = 25°C)		FC	40	٧٧	
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	



Weight: 5.8 g (typ.)

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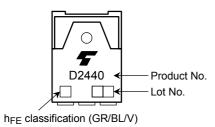


# **Electrical Characteristics (Ta = 25°C)**

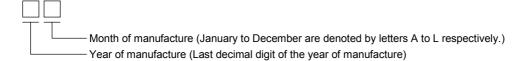
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off of	urrent	I <sub>CBO</sub>	V <sub>CB</sub> = 100 V, I <sub>E</sub> = 0	_	_	10	μΑ
Collector cut-off of	urrent	I <sub>CER</sub>	V <sub>CE</sub> = 80 V, R <sub>BE</sub> = 50 Ω	-	_	5	mA
Emitter cut-off cur	rrent	I <sub>EBO</sub>	V <sub>EB</sub> = 15 V, I <sub>C</sub> = 0	_	_	2	μΑ
Collector-emitter	breakdown voltage	V (BR) CEO	I <sub>C</sub> = 50 mA, I <sub>B</sub> = 0	60	_	_	V
DC current gain		h <sub>FE (1)</sub> (Note)	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 0.5 A	200	_	900	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 5 A	20	_	100	
Collector-emitter	saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = 5 A, I <sub>B</sub> = 1 A	_		1.2	V
Base-emitter satu	ration voltage	V <sub>BE (sat)</sub>	I <sub>C</sub> = 5 A, I <sub>B</sub> = 1 A	_		2.5	V
Transition frequency		f <sub>T</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 0.5 A	_	5	_	MHz
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	71	_	pF
Switching time	Turn-on time	t <sub>on</sub>	20 µs I <sub>B1</sub> Output		1	2	
	Storage time	t <sub>stg</sub>		_	2	4	μs
	Fall time	t <sub>f</sub>	$V_{CC} = 50 \text{ V}$ $I_{B1} = -I_{B2} = 0.5 \text{ A, duty cycle} \le 1\%$	_	1	3	

Note: hFE (1) classification GR: 200 to 400, BL: 300 to 600, V: 450 to 900

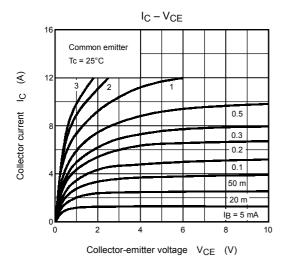
## Marking

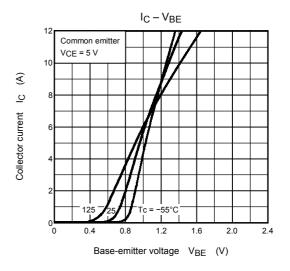


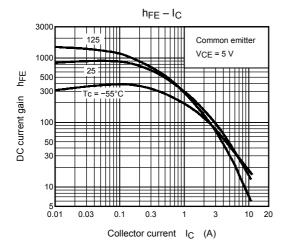
# **Explanation of Lot No.**

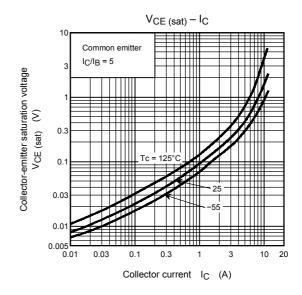


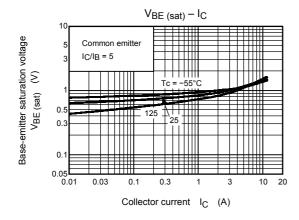
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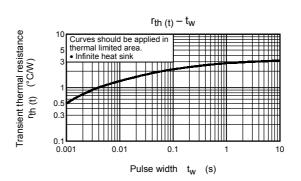


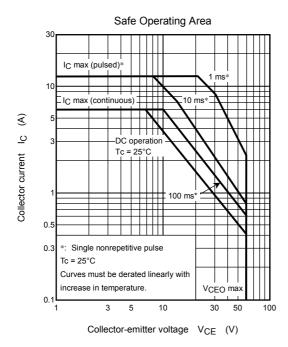












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